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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/015,701	12/17/2001	Kyeong Jin Kim	8733.479.00	6382
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	MCKENNA LONG & ALDRIDGE LLP 1900 K STREET, NW			иотну L
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	,		2883	
			DATE MAILED: 01/27/200	5

Please find below and/or attached an Office communication concerning this application or proceeding.

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	Application No.	Applicant(s)	- <del>\</del>
	10/015,701	KIM, KYEONG JIN	
Office Action Summary	Examiner	Art Unit	
	Timothy L Rude	2883	
The MAILING DATE of this communication		th the correspondence address -	-
Period for Reply			
A SHORTENED STATUTORY PERIOD FOR REI THE MAILING DATE OF THIS COMMUNICATIO  Extensions of time may be available under the provisions of 37 CFR after SIX (6) MONTHS from the mailing date of this communication.  If the period for reply specified above is less than thirty (30) days, a  If NO period for reply is specified above, the maximum statutory per Failure to reply within the set or extended period for reply will, by sta Any reply received by the Office later than three months after the may earned patent term adjustment. See 37 CFR 1.704(b).	N. 1.136(a). In no event, however, may a r reply within the statutory minimum of thir od will apply and will expire SIX (6) MON tute, cause the application to become AE	eply be timely filed y (30) days will be considered timely. THS from the mailing date of this communica ANDONED (35 U.S.C. § 133).	ition.
Status			
1) Responsive to communication(s) filed on 27	October 2004.		
2a)☐ This action is <b>FINAL</b> . 2b)☑ T	his action is non-final.		
3) Since this application is in condition for allow	wance except for formal matt	ers, prosecution as to the merits	is
closed in accordance with the practice unde	er <i>Ex par</i> te Quayle, 1935 C.D	. 11, 453 O.G. 213.	
Disposition of Claims			
4)⊠ Claim(s) 1-9 and 11-28 is/are pending in the	e application.		
4a) Of the above claim(s) <u>6,8,16 and 21-28</u> i	• •	eration.	
5) Claim(s) is/are allowed.			
6)⊠ Claim(s) <u>1-5,7,9,11-15 and 17-20</u> is/are reje	ected.		
7) Claim(s) is/are objected to.			
8) Claim(s) are subject to restriction and	d/or election requirement.		
Application Papers			
9)☐ The specification is objected to by the Exam	iner.		
10)☐ The drawing(s) filed on is/are: a)☐ a		by the Examiner.	•
Applicant may not request that any objection to t	he drawing(s) be held in abeyar	ce. See 37 CFR 1.85(a).	
Replacement drawing sheet(s) including the corr	,	•	• •
11) The oath or declaration is objected to by the	Examiner. Note the attached	Office Action or form PTO-152.	
Priority under 35 U.S.C. § 119			
12)☐ Acknowledgment is made of a claim for forei	gn priority under 35 U.S.C. §	119(a)-(d) or (f).	
a) ☐ All b) ☐ Some * c) ☐ None of:			
<ol> <li>Certified copies of the priority docume</li> </ol>	ents have been received.		
2. Certified copies of the priority docume		· · · · · · · · · · · · · · · · · · ·	
3. Copies of the certified copies of the p		received in this National Stage	
application from the International Bure  * See the attached detailed Office action for a I	,	racaivad	
See the attached detailed Office action for a r	iscordine cerdiled copies not	IECEIVEU.	
Attachment(s)			
) Notice of References Cited (PTO-892)		ummary (PTO-413)	
2) ☐ Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) ☐ Information Disclosure Statement(s) (PTO-1449 or PTO/SB/0		:)/Mail Date formal Patent Application (PTO-152)	٠
Paper No(s)/Mail Date	6)  Other:	<u>-</u> ·	

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## **DETAILED ACTION**

#### **Claims**

1. Claims 1-3, 5, and 11 are amended.

2. Claim 10 is canceled.

## Claim Objections

3. Claims 1, 11, and 20 are objected to because of the following informalities:

Claim 1 says the height difference between the dielectric frame and the sealant is

formed and then the substrates are attached. However, page 12, Table I, teaches the

after mated height differences and their associated effects which supports dependent

claims 10, 11, and 20. Page 11, [0051] simply states that primary and secondary cell

gaps are formed without any teaching as to sealant height prior to mating and without

any teaching as to how said gaps are established to be those of Table I. Appropriate

correction is required. New matter may be an issue. Please note that Applicant has

provided in the original presentation only enablement of the after mated height

difference; claim recitations may include specification of after mated height differences.

Claim 3 is objected to because of the following informalities: The recitation "sealant structure includes a double structure" is not adequately supported in the Specification or drawings. It is not clear what Applicant means by the only reference in

the Specification, Page 10 [0050]. For examination purposes "sealant structure includes a double structure" will be interpreted as anything pertaining to sealant structure that is double. Appropriate correction is required. New matter may be an issue. Please note that most displays have sealant on four sides of a rectangular display area which may be broadly interpreted as a contiguous quad structure that reads on Applicant's claimed double structure. Examiner believes there is no support in the specification for narrowing Applicant's claimed double structure.

Claim 5 is objected to because of the following informalities: The recitation "hole shape" is not clear. A hole may have most any shape. For examination purposes "slit shape or hole shape" will be interpreted as any shape of hole or slit. Appropriate correction is required.

Objection to claim 7 is withdrawn.

## Claim Rejections - 35 USC § 112

4. Rejection of claim 7 under 35 U.S.C. 112, first paragraph, as failing to comply with the written description requirement is withdrawn. Examiner is aware of prior publications by Applicant that are and were considered adequate justification for the amendment to the specification that added the recitations as to channel shape without it being considered new matter.

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## Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

- (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 5. Claims 1 and 7 are rejected under 35 U.S.C. 103(a) as being unpatentable over Oh et al (Oh) USPAT 6,130,729 in view of Liu et al (Liu) USPAT 6,573,965 B1 and further in view of Von Gutfeld et al (Von Gutfeld) USPAT 6,055,035.

As to claims 1 and 7 Ohe discloses (Abstract and entire patent) a method of forming a liquid crystal display device comprising: forming an L-shaped thin film transistor (Figure 3A, col. 6, lines 32-37) and a pixel electrode, 39, on a first substrate.

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FIG. 3A

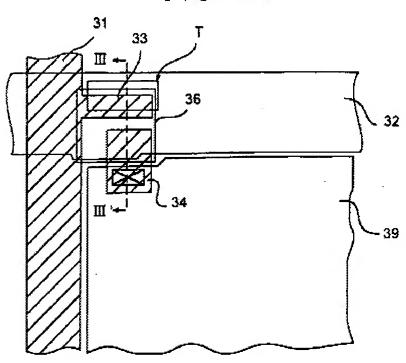
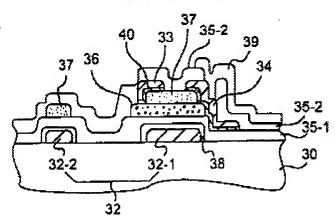


FIG. 3B

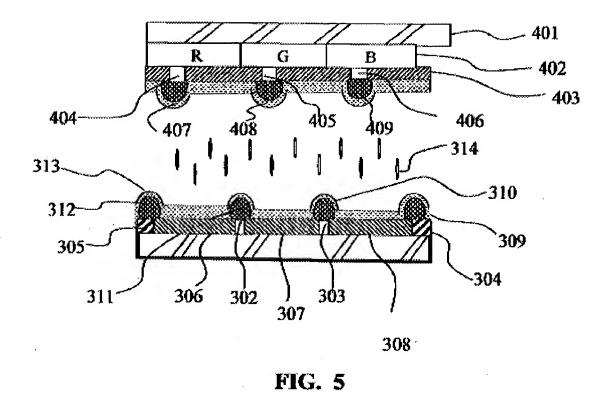


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Ohe does not explicitly disclose forming a dielectric frame having a first height and a sealant having a second height on a second substrate, the first height of the dielectric frame being different from the second height of the sealant; dispensing liquid crystal on the first substrate; and attaching the first and second substrates to each other.

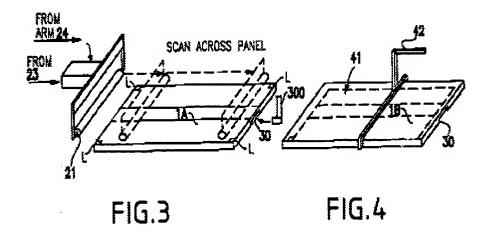
Liu teaches (Abstract and entire patent) forming bumps, 311 and 409 (Applicant's dielectric frame) on both substrates (Figure 5, col. 5, lines 45-57, and col. 5, lines 35-44) having a first height and a sealant having a second height (not shown) such that the sealant is taller than the dielectric frame as is evidenced by the gap between the dielectric frames and the opposed substrate (Figure 5) to comprise a multi-domain display with wide viewing angle (col. 2, lines 36-46).

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Von Gutfeld teaches dispensing liquid crystal on the first substrate (Abstract and entire patent); and attaching the first and second substrates to each other to provide a simplified and more efficient method for filling an unassembled LCD panel that is less costly (col. 2, lines 25-34).

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Liu is evidence that ordinary workers in the art of liquid crystals would find the reason, suggestion, or motivation to add a dielectric frame on both substrates having a first height and a sealant having a second height such that the sealant is taller than the dielectric frame to comprise a multi-domain display with wide viewing angle.

Von Gutfeld is evidence that ordinary workers in the art of liquid crystals would find the reason, suggestion, or motivation to dispense liquid crystal on the first substrate; and attach the first and second substrates to each other to provide a simplified and more efficient method for filling an unassembled LCD panel that is less costly.

Therefore, it would have been obvious to one having ordinary skill in the art of liquid crystals at the time the invention was made to modify the LCD of Oh with the dielectric frame on both substrates having a first height and a sealant having a second height such that the sealant is taller than the dielectric frame of Liu to comprise a multidomain display with wide viewing angle and to dispense liquid crystal on the first

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substrate; and attach the first and second substrates to each other per Von Gutfeld to provide a simplified and more efficient method for filling an unassembled LCD panel that is less costly.

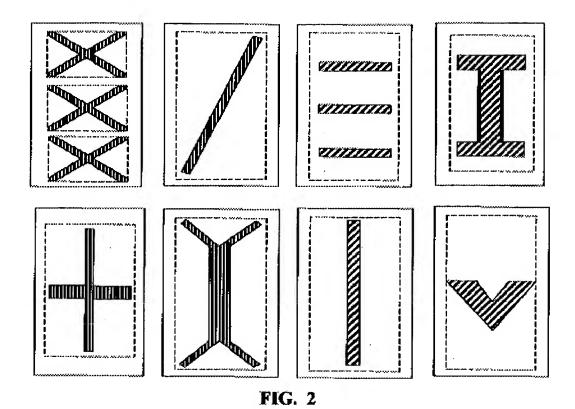
As to claim 2, Von Gutfeld, as combined above, teaches that the sealant includes a material hardened by ultraviolet ray (col. 4, lines 1-4).

As to claim 3, Von Gutfeld, as combined above, teaches that the sealant includes a double sealant structure in that there is a seal on the right and a seal on the left. Von Gutfeld teaches that the sealant includes a double sealant structure in that there is a seal on the top and a seal on the bottom. Also, please note that mere duplication of the essential working parts of a device involves only routine skill in the art. For example additional redundant seal boarders inside or outside a first seal would be considered mere duplication of parts, not a patentably distinct species, unless unexpected results were obtained.

As to claim 4 Liu, as combined above, teaches a method further comprising forming electric field inducing slits, 302 and 303 (Applicant's windows), in the pixel electrode, 306~308.

As to claim 5, Liu, as combined above, teaches in Figure 2 a method wherein the electric field inducing window has a slit shape or a hole shape.

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As to claim 9, Liu, as combined above, teaches Prior Art in Figure 1 that shows dielectric frames drive the liquid crystal in various directions.

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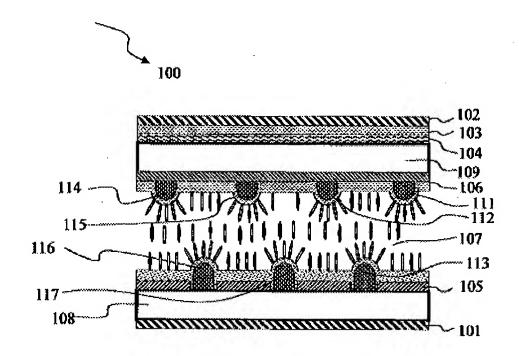


FIG. 1 (Prior Art)

As to claim 12, Oh, as combined above, discloses a method further comprising forming a common electrode on the second substrate (required element, not shown).

As to claim 13, Liu, as combined above, teaches a method wherein the dielectric frame, 409, is formed on the common electrode, 403 (Figure 5).

As to claim 14, Liu, as combined above, teaches a method further comprising forming an alignment layer, 313 and 407, on the first and second substrates (Figure 5).

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6. Claims 11 and 20 are rejected under 35 U.S.C. 103(a) as being unpatentable over Oh, Liu, and Von Gutfeld, as applied to claims above, in view of Kishimoto et al (Kishimoto) USPAT 6,515,718 B1.

As to claims 11 and 20, Oh, Liu, and Von Gutfeld disclose the method above.

Oh, Liu, and Von Gutfeld do not explicitly disclose specific heights of dielectric structures with respect to seal heights wherein a height difference between the sealant and the dielectric frame is more than 1 µm or wherein the first height is a range of 1-2 µm and the second height is in a range of 5-8 µm.

Please note the motivations for establishing cell gap (and correspondingly seal height) were well known in the art at the time the claimed invention was made and include optimization of voltage required, retarder value of liquid crystal layer, and control of liquid crystal mode or configuration.

Kishimoto discloses the motivation to optimize the height of a dielectric structure is to account for the relative dielectric constants of the respective components (col. 18, lines 21-23). In other words, the height is made sufficient to achieve the desired dielectric effect given the relative dielectric strength of the material used.

Kishimoto is evidence that ordinary workers in the art of liquid crystals would find the reason, suggestion, or motivation to optimize the results effective variables of relative dielectric frame height and seal height to achieve the desired dielectric effect given the relative dielectric strength of the material used.

Therefore, it would have been obvious to one having ordinary skill in the art of liquid crystals at the time the invention was made to modify the LCD of Oh, Liu, and Von Gutfeld with the specific heights of dielectric structures with respect to seal heights wherein a height difference between the sealant and the dielectric frame is more than 1 µm or wherein the first height is a range of 1-2 µm and the second height is in a range of 5-8 µm of Kishimoto to achieve the desired dielectric effect given the relative dielectric strength of the material used (MPEP 2144.05, II, B).

7. Claim 15 is rejected under 35 U.S.C. 103(a) as being unpatentable over Oh, Liu, and Von Gutfeld, as applied to claims above, in view of Tanaka et al (Tanaka) USPAT 6,603,528 B1.

As to claim 15, Oh, Liu, and Von Gutfeld disclose the method of claim 14.

Oh, Liu, and Von Gutfeld do not explicitly disclose a method wherein the alignment layer is selected from the group consisting of polyimide, polyamide, polyvinyl alcohol, polyamic acid, and silicon oxide.

Tanaka teaches the use of polyimide as an art recognized material suitable for the intended purpose of forming an alignment film for liquid crystal displays (col. 9, lines 5-21).

Tanaka is evidence that ordinary workers in the art of liquid crystals would find the reason, suggestion, or motivation to use polyimide as an art recognized material suitable for the intended purpose of forming an alignment film for liquid crystal displays.

Therefore, it would have been obvious to one having ordinary skill in the art of liquid crystals at the time the invention was made to modify the LCD of Oh, Liu, and Von Gutfeld with the polyimide alignment layer of Tanaka as an art recognized material suitable for the intended purpose of forming an alignment film for liquid crystal displays (MPEP 2144.07).

8. Claims 17-19 are rejected under 35 U.S.C. 103(a) as being unpatentable over Oh, Liu, and Von Gutfeld, as applied to claims above, in view of Kim et al (Kim) USPAT 6,100,953.

As to claims 17-19, Oh, Liu, and Von Gutfeld disclose the method of claim 14.

Oh, Liu, and Von Gutfeld do not explicitly disclose a method comprising formation of a phase difference film, negative uniaxial, or negative biaxial.

Kim teaches the use of negative uniaxial and negative biaxial phase compensation films (Applicant's phase difference films) as suitable means of improving viewing angle performance (col. 5, line 66, through col. 6, line 12).

Kim is evidence that ordinary workers in the art of liquid crystals would find the reason, suggestion, or motivation to add negative uniaxial and negative biaxial phase difference films as suitable means of improving viewing angle performance.

Therefore, it would have been obvious to one having ordinary skill in the art of liquid crystals at the time the invention was made to modify the LCD of Oh, Liu, and Von Gutfeld with the negative uniaxial and negative biaxial phase difference films of Kim as suitable means of improving viewing angle performance.

#### Response to Arguments

9. Applicant's arguments filed on 02 September 2004 and 27 October 2004 have been fully considered but they are not persuasive.

### Applicant's ONLY arguments are as follows:

- (1) Applied references do not teach forming a dielectric frame having a first height and a sealant having a second height different from said first height.
  - (2) Kishimoto does not disclose adequate motivation to achieve claimed heights.
  - (3) Dependent claims are allowable because the independent claim is allowable.

# Examiner's responses to Applicant's ONLY arguments are as follows:

(1) It is respectfully pointed out that the applied references clearly teach forming a dielectric frame having a first height and a sealant having a second height different from said first height because the finished device has a sealant taller than the dielectric

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frame [dielectric frames are shorter than the distance between substrates, and the seal must reach all the way from one substrate to the other] which necessitates the claimed difference.

(2) It is respectfully pointed out that optimization of a results effective variable requires only routine experimentation [MPEP 2144.05, II, B].

(3) In so far as Applicant has not argued rationale for rejection of the dependent claims Applicant has thereby acquiesced.

#### Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Timothy L Rude whose telephone number is (571) 272-2301. The examiner can normally be reached on Monday through Thursday.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Frank Font can be reached on (571) 272-2415. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

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Timothy L Rude Examiner

Art Unit 2883

tlr

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